

Data Sheet January 2000 File Number 2772.4

30A, 400V - 600V Ultrafast Dual Diodes

RURH3040CC and RURH3060CC are ultrafast dual diodes ($t_{rr} < 55$ ns) with soft recovery characteristics. They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction.

These devices are intended for use as energy steering/ clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor.

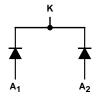
Formerly developmental type TA09903.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RURH3040CC	TO-218AC	RURH3040C
RURH3060CC	TO-218AC	RURH3060C

NOTE: When ordering, use the entire part number.

Symbol



Features

•	Ultrafast with Soft Recovery<55ns
•	Operating Temperature
•	Reverse Voltage Up to

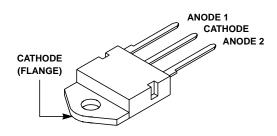
- Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supply
- · Power Switching Circuits
- · General Purpose

Packaging

JEDEC TO-218AC



Absolute Maximum Ratings (Per Leg) T _C = 25°C, Unless Otherwise Specified			
	RURH3040CC	RURH3060CC	UNITS
Peak Repetitive Reverse VoltageV _{RRM}	400	600	V
Working Peak Reverse Voltage	400	600	V
DC Blocking VoltageV _R	400	600	V
Average Rectified Forward Current	30	30	Α
Repetitive Peak Surge Current	70	70	Α
Nonrepetitive Peak Surge Current	325	325	Α
Maximum Power Dissipation	125	125	W
Avalanche Energy (See Figures 7 and 8)	20	20	mJ
Operating and Storage Temperature	-55 to 175	-55 to 175	oC

RURH3040CC, RURH3060CC

Electrical Specifications (Per Leg) $T_C = 25^{\circ}C$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	MIN	TYP	MAX	UNITS
V _F	I _F = 30A	-	-	1.5	-	-	1.5	V
	$I_F = 30A, T_C = 150^{\circ}C$	-	-	1.3	-	-	1.3	V
I _R	V _R = 400V	-	-	250	-	-	-	μΑ
	V _R = 600V	-	-	-	-	-	250	μΑ
	$V_R = 400V, T_C = 150^{\circ}C$	-	-	1	-	-	-	mA
	$V_R = 600V, T_C = 150^{\circ}C$	-	-	-	-	-	1	mA
t _{rr}	$I_F = 1A$, $d_{IF}/dt = 100A/\mu s$	-	-	55	-	-	55	ns
	$I_F = 30A$, $d_{IF}/dt = 100A/\mu s$	-	-	60	-	-	60	ns
ta	$I_F = 30A$, $d_{IF}/dt = 100A/\mu s$	-	30	-	-	30	-	ns
t _b	$I_F = 30A$, $d_{IF}/dt = 100A/\mu s$	-	20	-	-	20	-	ns
$R_{ heta JC}$		-	-	1.2	-	-	1.2	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time at dI_F/dt = 100A/ μ s (See Figure 6), summation of t_a + t_b .

 t_a = Time to reach peak reverse current at dI_F/dt = 100A/ μ s (See Figure 6).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 6).

 $R_{\theta,JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

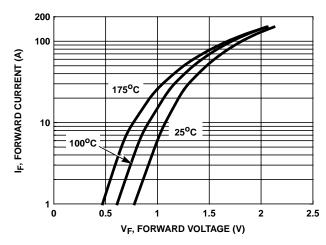


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

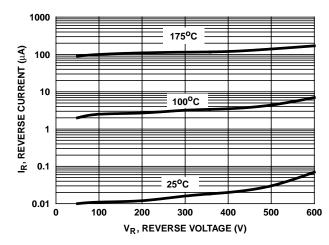


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

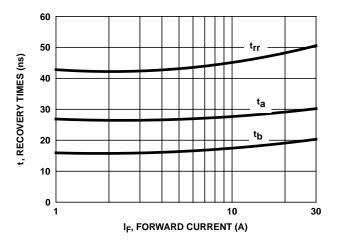


FIGURE 3. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

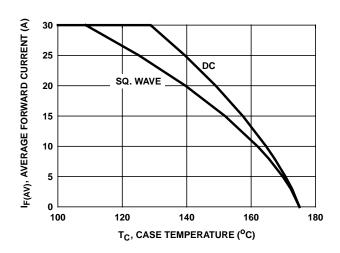


FIGURE 4. CURRENT DERATING CURVE

Test Circuits and Waveforms

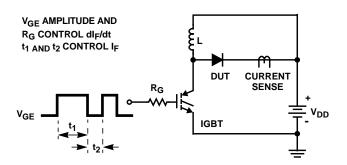


FIGURE 5. t_{rr} TEST CIRCUIT

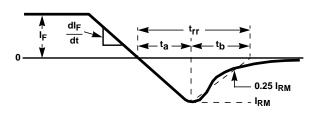


FIGURE 6. t_{rr} WAVEFORMS AND DEFINITIONS

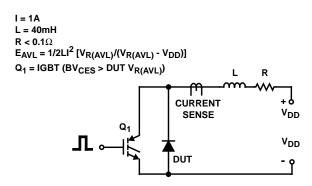


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

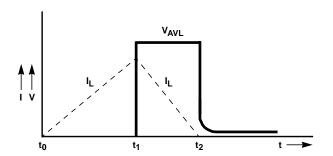


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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